N-channel TrenchMOS standard level FET

2. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-----------------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | G | gate | | _ |
| 2 | d | drain | mb | |
| 3 | S | source | | |
| mb | D | mounting base; connected to drain | | mbb076 S |
| | | | SOT428 (DPAK) | |

3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|---|---------|
| | Name | Description | Version |
| BUK7219-55A | DPAK | plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped) | SOT428 |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

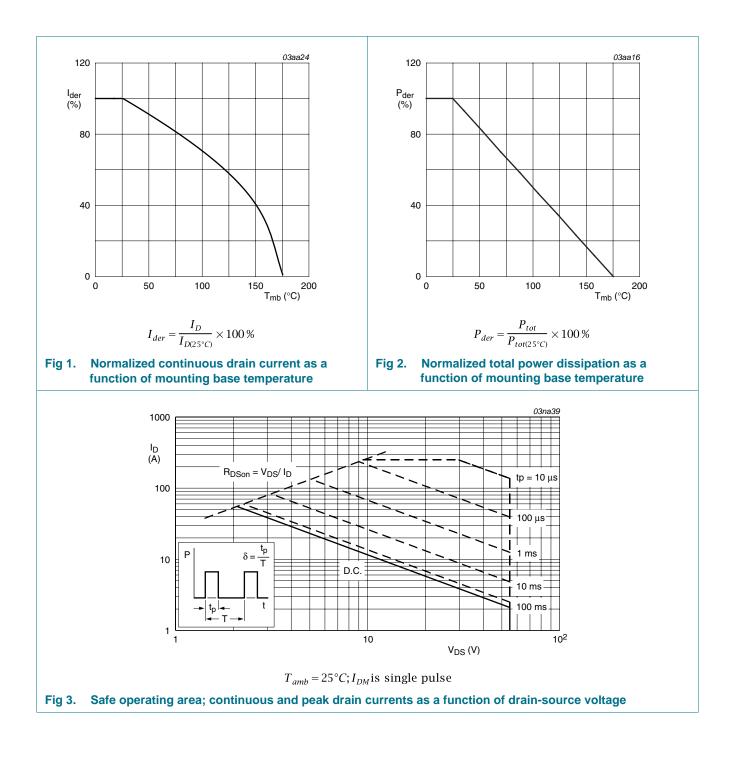
| Symbol | Parameter | Conditions | | Min | Мах | Unit |
|----------------------|--|--|------------|-----|-----|------|
| V _{DS} | drain-source voltage | T _j ≥ 25 °C; T _j ≤ 175 °C | | - | 55 | V |
| V _{DGR} | drain-gate voltage | $R_{GS} = 20 \ k\Omega$ | | - | 55 | V |
| V _{GS} | gate-source voltage | | | -20 | 20 | V |
| I _D | drain current | T_{mb} = 100 °C; V_{GS} = 5 V; see <u>Figure 1</u> | | - | 39 | А |
| | | T_{mb} = 25 °C; V_{GS} = 5 V; see <u>Figure 1</u> and <u>3</u> | | - | 55 | А |
| I _{DM} | peak drain current | T_{mb} = 25 °C; $t_p \le 10 \ \mu$ s; pulsed; see Figure 3 | <u>[1]</u> | - | 250 | А |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; see <u>Figure 2</u> | | - | 114 | W |
| T _{stg} | storage temperature | | | -55 | 175 | °C |
| Tj | junction temperature | | | -55 | 175 | °C |
| Avalanch | e ruggedness | | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | $ I_D = 49 \text{ A}; \text{V}_{\text{sup}} \leq 55 \text{ V}; \text{R}_{\text{GS}} = 50 \Omega; \text{V}_{\text{GS}} = 10 \text{ V}; \\ \text{T}_{j(\text{init})} = 25 ^{\circ}\text{C}; \text{ unclamped} $ | | - | 120 | mJ |
| Source-dr | rain diode | | | | | |
| I _S | source current | T _{mb} = 25 °C | | - | 55 | А |
| I _{SM} | peak source current | $t_p \le 10 \ \mu s$; pulsed; $T_{mb} = 25 \ ^{\circ}C$ | | - | 250 | А |

[1] Peak drain current is limited by chip, not package.

| BUK7219-55A_2 | |
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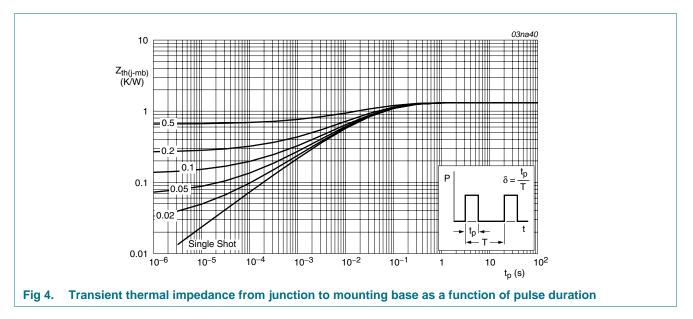
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5. Thermal characteristics

| Table 5. | Thermal characteristics | | | | | | | |
|-----------------------|---|--------------|-----|------|-----|------|--|--|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit | | |
| R _{th(j-mb)} | thermal resistance from junction to mounting base | | - | - | 1.3 | K/W | | |
| R _{th(j-a)} | thermal resistance from junction to ambient | see Figure 4 | - | 71.4 | - | K/W | | |



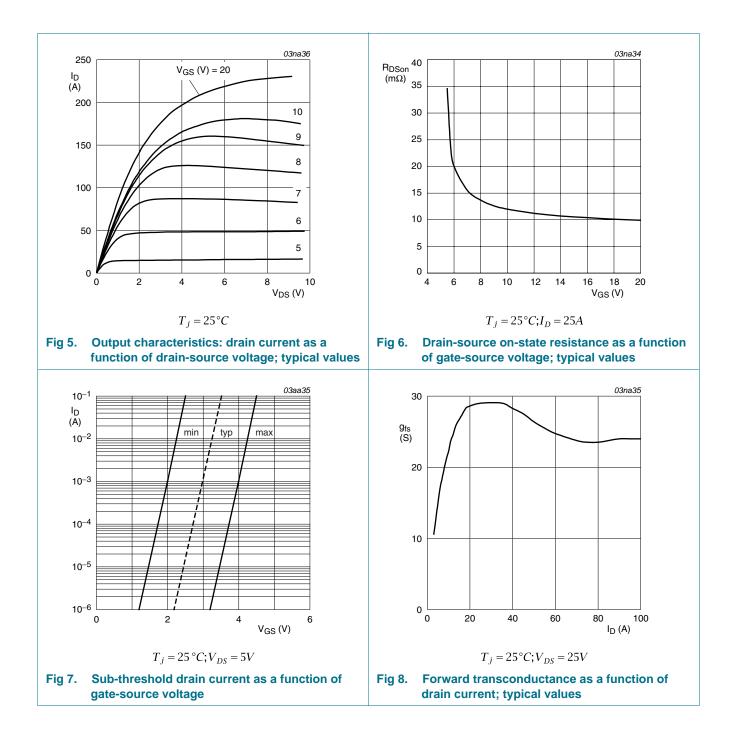
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6. Characteristics

| Table 6. | Characteristics | | | | | |
|----------------------|-------------------------------------|--|-----|------|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Static cha | aracteristics | | | | | |
| V _{(BR)DSS} | drain-source | $I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | 55 | - | - | V |
| | breakdown voltage | $I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = -55 \text{ °C}$ | 50 | - | - | V |
| V _{GS(th)} | gate-source threshold voltage | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ see <u>Figure 11</u> | 2 | 3 | 4 | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ see <u>Figure 11</u> | - | - | 4.4 | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ see <u>Figure 11</u> | 1 | - | - | V |
| I _{DSS} | drain leakage current | $V_{DS} = 55 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | - | 0.05 | 10 | μA |
| | | $V_{DS} = 55 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 175 \text{ °C}$ | - | - | 500 | μA |
| I _{GSS} | gate leakage current | $V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V}; T_j = 25 \text{ °C}$ | - | 2 | 100 | nA |
| | | $V_{DS} = 0 \text{ V}; V_{GS} = -10 \text{ V}; T_j = 25 \text{ °C}$ | - | 2 | 100 | nA |
| R _{DSon} | drain-source on-state resistance | V_{GS} = 10 V; I_D = 25 A; T_j = 175 °C; see <u>Figure 12</u> and <u>13</u> | - | - | 38 | mΩ |
| | | V_{GS} = 10 V; I _D = 25 A; T _j = 25 °C; see <u>Figure 12</u> and <u>13</u> | - | 16 | 19 | mΩ |
| Dynamic | characteristics | | | | | |
| C _{iss} | input capacitance | $V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz;$ | - | 1581 | 2108 | pF |
| C _{oss} | output capacitance | $T_j = 25 \text{ °C}; \text{ see } Figure 15$ | - | 372 | 446 | pF |
| C _{rss} | reverse transfer capacitance | | - | 221 | 303 | pF |
| t _{d(on)} | turn-on delay time | $V_{DS} = 30 \text{ V}; \text{ R}_{L} = 1.2 \Omega; \text{ V}_{GS} = 5 \text{ V};$ | - | 16 | - | ns |
| t _r | rise time | $R_{G(ext)} = 10 \ \Omega; T_j = 25 \ ^{\circ}C$ | - | 70 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 57 | - | ns |
| t _f | fall time | | - | 41 | - | ns |
| L _D | internal drain inductance | measured from drain lead from package to centre of die; $T_j = 25 \text{ °C}$ | - | 2.5 | - | nH |
| L _S | internal source inductance | measured from source lead from package to source bond pad; T _j = 25 °C | - | 7.5 | - | nH |
| Source-d | rain diode | | | | | |
| V _{SD} | source-drain voltage | I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; see <u>Figure 14</u> | - | 0.85 | 1.2 | V |
| t _{rr} | reverse recovery time | $I_S = 25 \text{ A}; \text{ dI}_S/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = -10 \text{ V};$ $V_{DS} = 30 \text{ V}; \text{ T}_j = 25 \ ^{\circ}\text{C}$ | - | 48 | - | ns |
| Q _r | recovered charge | | - | 106 | - | nC |

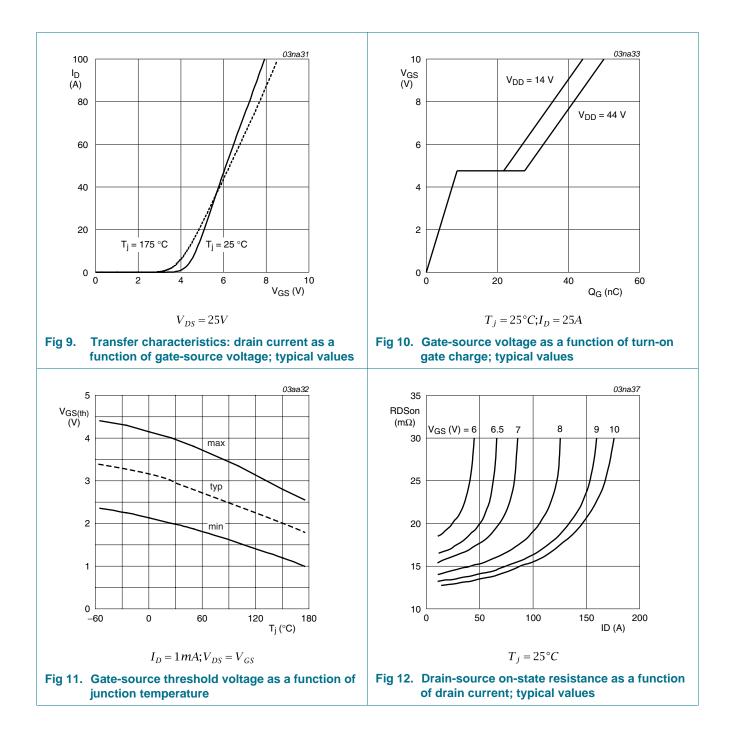
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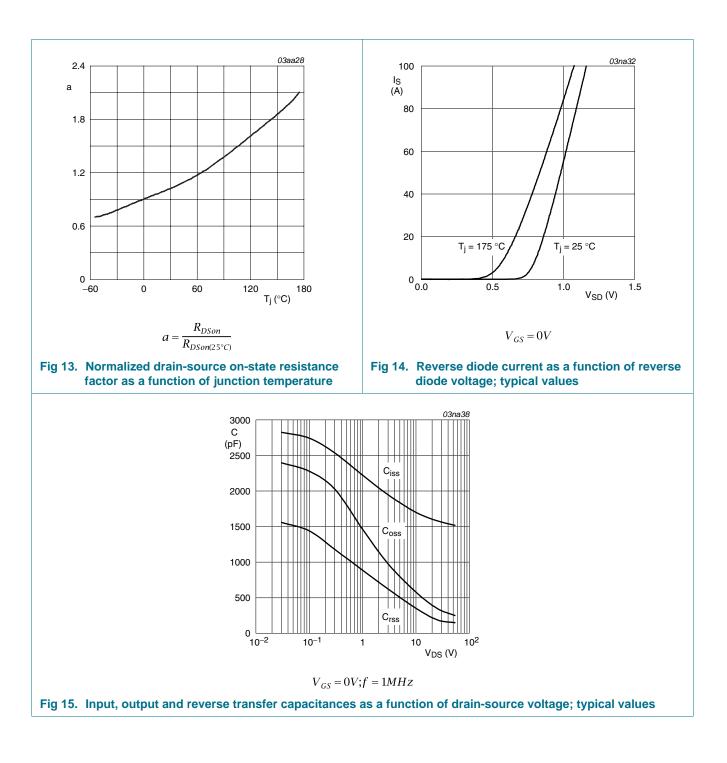
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7. Package outline

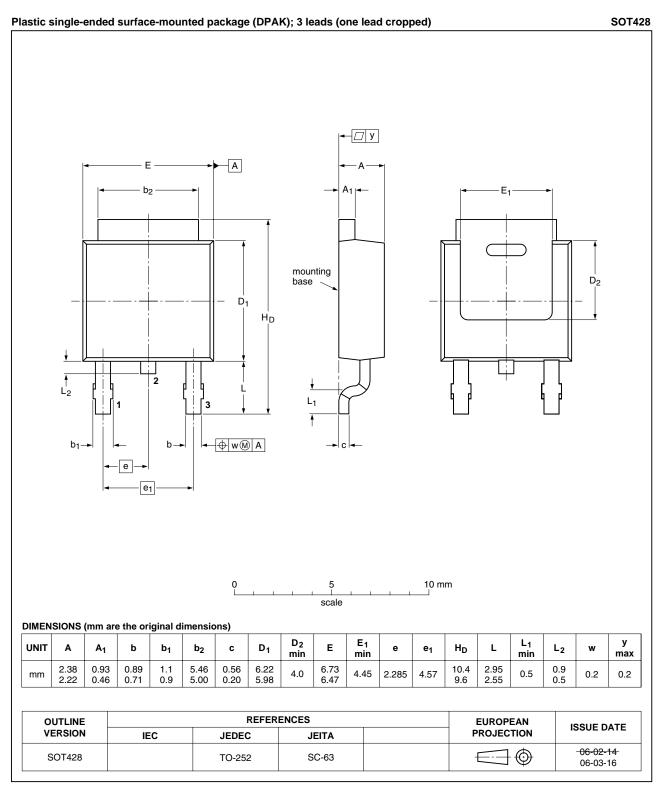


Fig 16. Package outline SOT428 (DPAK)

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8. Revision history

| Table 7. Revision his | tory | | | |
|------------------------------------|---------------------------------|---|-----------------------|-------------------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| BUK7219-55A_2 | 20100203 | Product data sheet | - | BUK7219-55A-01 |
| Modifications: | | t of this data sheet has be of NXP Semiconductors. | • . | y with the new identity |
| | Legal texts | have been adapted to the | ne new company name v | vhere appropriate. |
| BUK7219-55A-01 (9397 750 07575) | 20001002 | Product specification | - | - |

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9. Legal information

9.1 Data sheet status

| Document status [1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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